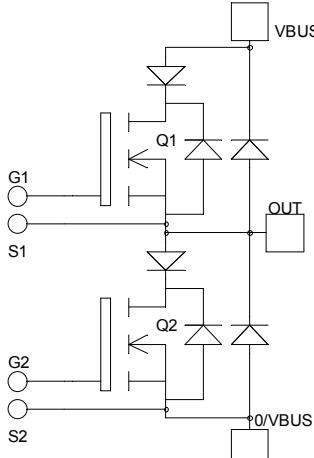


Phase leg
Series & parallel diodes
MOSFET Power Module

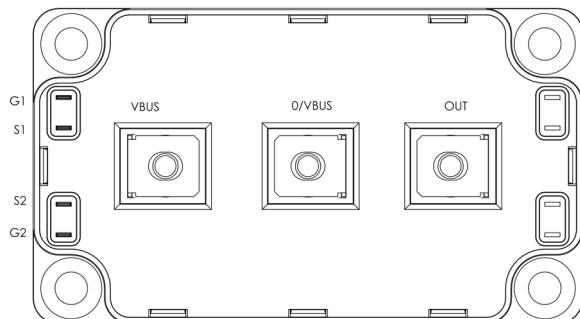
V_{DSS} = 500V
R_{DSon} = 24mΩ typ @ T_j = 25°C
I_D = 150A @ T_c = 25°C


Application

- Motor control
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration


Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

All ratings @ T_j = 25°C unless otherwise specified

Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit
V _{DSS}	Drain - Source Breakdown Voltage	500	V
I _D	Continuous Drain Current	T _c = 25°C	A
		T _c = 80°C	
I _{DM}	Pulsed Drain current	600	
V _{GS}	Gate - Source Voltage	±30	V
R _{DSon}	Drain - Source ON Resistance	28	mΩ
P _D	Maximum Power Dissipation	T _c = 25°C	W
I _{AR}	Avalanche current (repetitive and non repetitive)	24	A
E _{AR}	Repetitive Avalanche Energy	30	
E _{AS}	Single Pulse Avalanche Energy	1300	mJ

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com

Electrical Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
I _{DSS}	Zero Gate Voltage Drain Current	V _{GS} = 0V, V _{DS} = 500V			500	µA
R _{DS(on)}	Drain – Source on Resistance	V _{GS} = 10V, I _D = 75A		24	28	mΩ
V _{GS(th)}	Gate Threshold Voltage	V _{GS} = V _{DS} , I _D = 6mA	3		5	V
I _{GSS}	Gate – Source Leakage Current	V _{GS} = ±30 V, V _{DS} = 0V			±600	nA

Dynamic Characteristics

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
C _{iss}	Input Capacitance	V _{GS} = 0V V _{DS} = 25V f = 1MHz		19.6		nF
C _{oss}	Output Capacitance			4.2		
C _{rss}	Reverse Transfer Capacitance			0.3		
Q _g	Total gate Charge	V _{GS} = 10V V _{Bus} = 250V I _D = 150A		434		nC
Q _{gs}	Gate – Source Charge			120		
Q _{gd}	Gate – Drain Charge			216		
T _{d(on)}	Turn-on Delay Time		10			ns
T _r	Rise Time	V _{GS} = 15V V _{Bus} = 333V I _D = 150A R _G = 0.8Ω	17			
T _{d(off)}	Turn-off Delay Time		50			
T _f	Fall Time		41			
E _{on}	Turn-on Switching Energy	Inductive switching @ 25°C V _{GS} = 15V, V _{Bus} = 333V I _D = 150A, R _G = 0.8Ω	1.9			mJ
E _{off}	Turn-off Switching Energy		1.5			
E _{on}	Turn-on Switching Energy	Inductive switching @ 125°C V _{GS} = 15V, V _{Bus} = 333V I _D = 150A, R _G = 0.8Ω	3.3			mJ
E _{off}	Turn-off Switching Energy		1.7			
R _{thJC}	Junction to Case Thermal Resistance				0.1	°C/W

Series diode ratings and characteristics

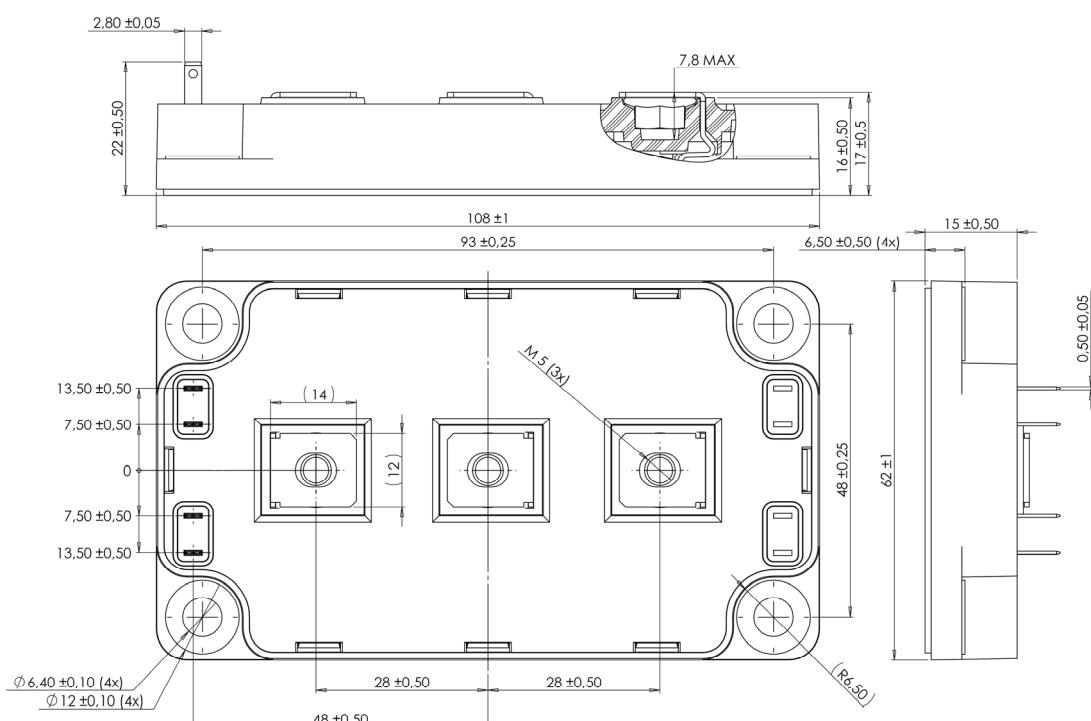
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
V _{RRM}	Maximum Peak Repetitive Reverse Voltage		600			V
I _{RM}	Maximum Reverse Leakage Current	V _R =600V			150	µA
I _F	DC Forward Current		T _c = 80°C	200		A
V _F	Diode Forward Voltage	I _F = 200A V _{GE} = 0V	T _j = 25°C	1.6	2	V
			T _j = 150°C	1.5		
t _{rr}	Reverse Recovery Time	I _F = 200A V _R = 300V di/dt = 2800A/µs	T _j = 25°C	125		ns
			T _j = 150°C	220		
Q _{rr}	Reverse Recovery Charge	T _j = 25°C	9.4			µC
			T _j = 150°C	19.8		
E _r	Reverse Recovery Energy	T _j = 25°C	2.2			mJ
			T _j = 150°C	4.8		
R _{thJC}	Junction to Case Thermal Resistance				0.39	°C/W

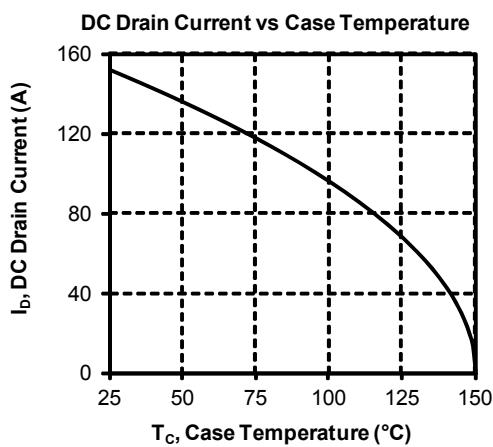
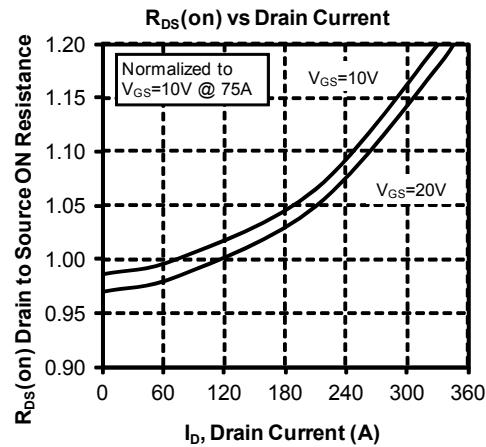
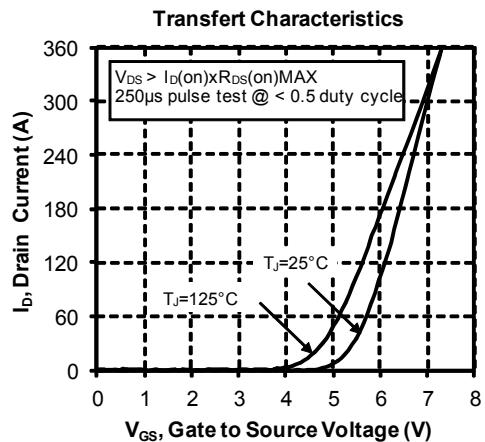
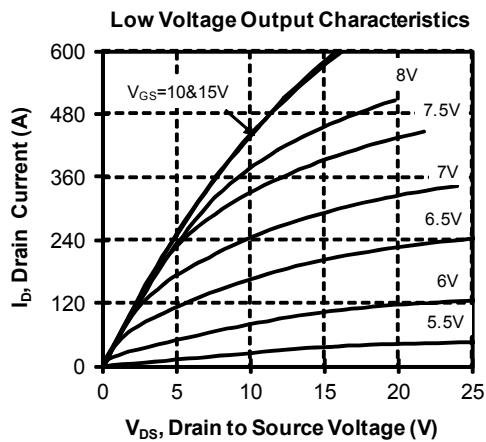
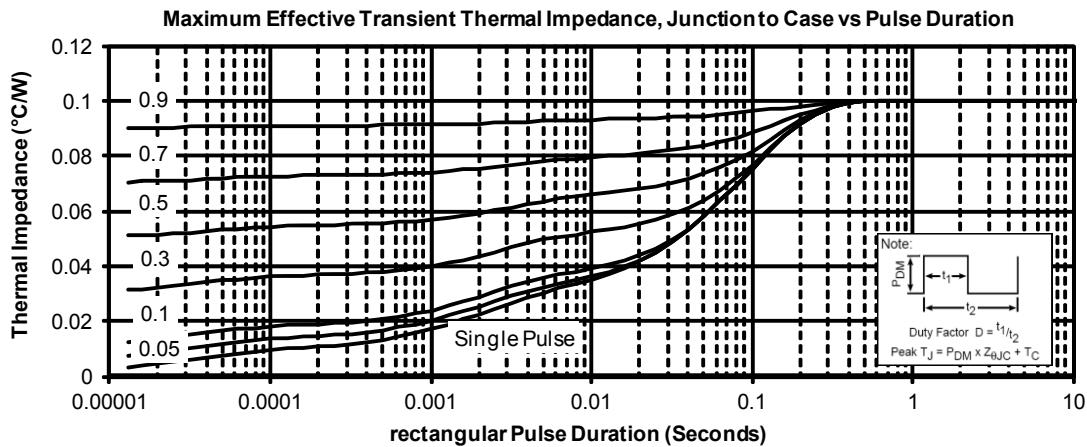
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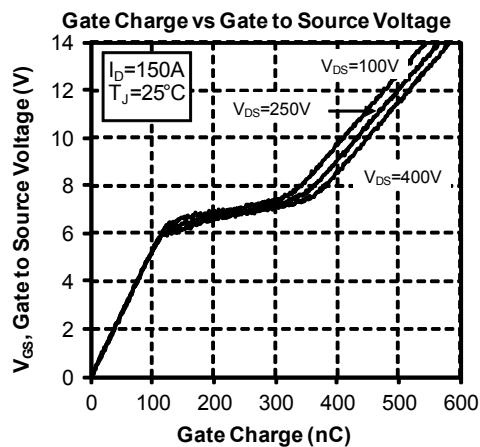
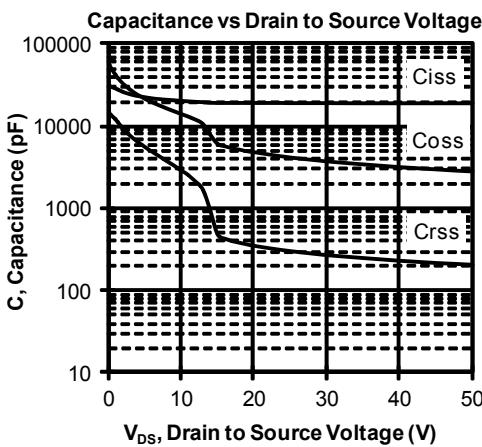
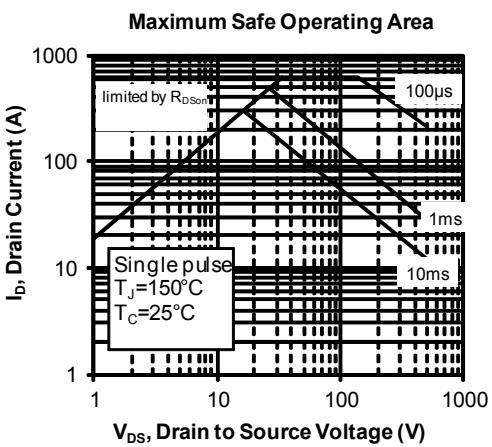
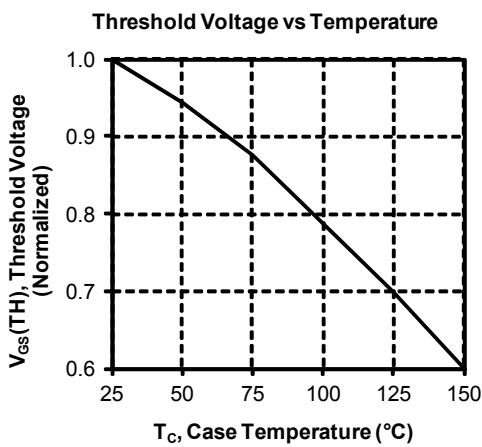
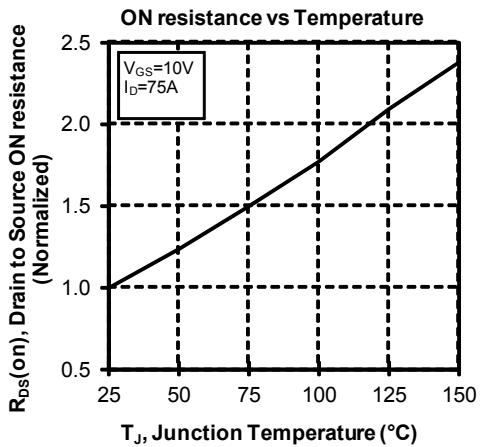
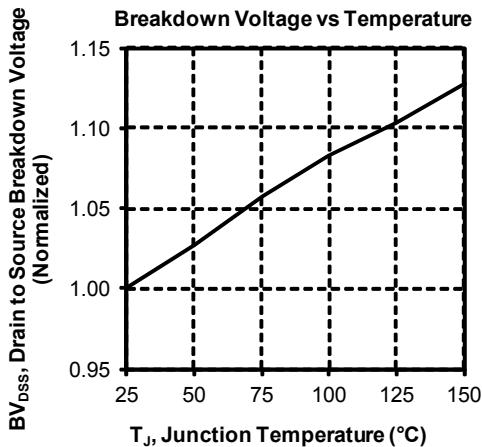
Symbol	Characteristic	Test Conditions		Min	Typ	Max	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage			600			V
I_{RM}	Maximum Reverse Leakage Current	$V_R = 600V$				350	μA
I_F	DC Forward Current			$T_c = 70^\circ C$	120		A
V_F	Diode Forward Voltage	$I_F = 120A$			1.6	1.8	V
		$I_F = 240A$			1.9		
		$I_F = 120A$	$T_j = 125^\circ C$		1.4		
t_{rr}	Reverse Recovery Time	$I_F = 120A$		$T_j = 25^\circ C$	130		ns
		$V_R = 400V$		$T_j = 125^\circ C$	170		
Q_{rr}	Reverse Recovery Charge	$di/dt = 400A/\mu s$		$T_j = 25^\circ C$	440		nC
				$T_j = 125^\circ C$	1840		
R_{thJC}	Junction to Case Thermal Resistance					0.46	$^\circ C/W$

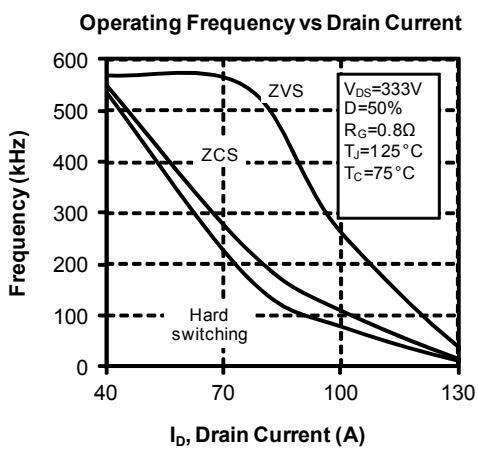
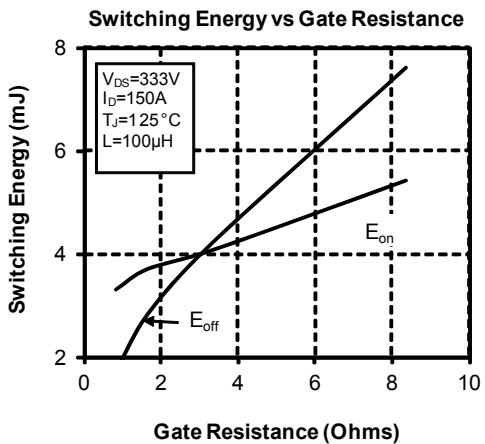
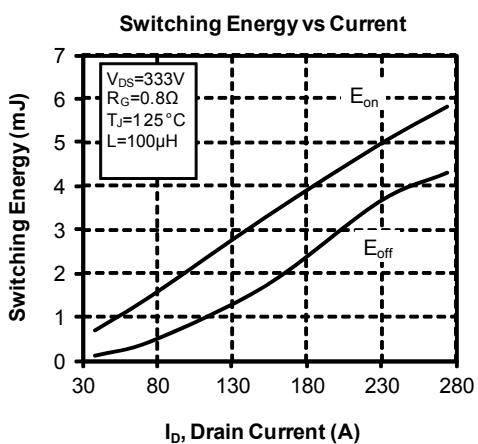
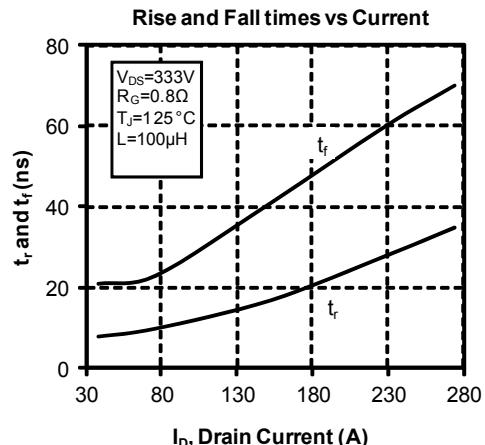
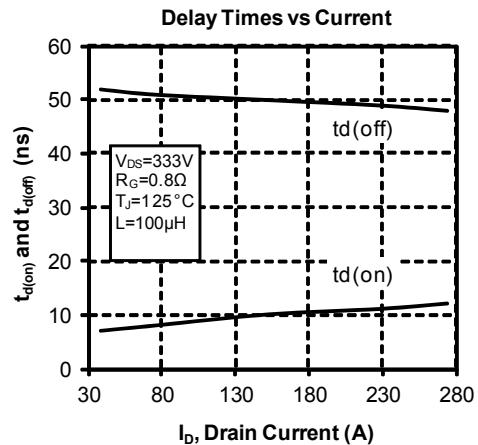
Thermal and package characteristics

Symbol	Characteristic	Min	Max	Unit
V_{ISOL}	RMS Isolation Voltage, any terminal to case $t = 1$ min, 50/60Hz	4000		V
T_j	Operating junction temperature range	-40	150	$^\circ C$
T_{JOP}	Recommended junction temperature under switching conditions	-40	$T_{jmax} - 25$	
T_{STG}	Storage Temperature Range	-40	125	
T_c	Operating Case Temperature	-40	100	
Torque	Mounting torque	To heatsink	M6	3
		For terminals	M5	2
Wt	Package Weight			300
				g

SP6 Package outline (dimensions in mm)

 See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

Typical Performance Curve






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